

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (L²-π-MOSV)

2SK2233

Chopper Regulator, DC-DC Converter and Motor Drive Applications

Unit: mm

- 4-V gate drive
- Low drain-source ON resistance : $R_{DS(ON)} = 0.022 \Omega$ (typ.)
- High forward transfer admittance : $|Y_{fs}| = 27 S$ (typ.)
- Low leakage current : $I_{DSS} = 100 \mu A$ (max) ($V_{DS} = 60 V$)
- Enhancement mode : $V_{th} = 0.8$ to $2.0 V$ ($V_{DS} = 10 V$, $I_D = 1 mA$)

Absolute Maximum Ratings ($T_a = 25^\circ C$)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	60	V
Drain-gate voltage ($R_{GS} = 20 k\Omega$)	V_{DGR}	60	V
Gate-source voltage	V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	A
	Pulse (Note 1)	I_{DP}	A
Drain power dissipation ($T_c = 25^\circ C$)	P_D	100	W
Single pulse avalanche energy (Note 2)	E_{AS}	246	mJ
Avalanche current	I_{AR}	45	A
Repetitive avalanche energy (Note 3)	E_{AR}	10	mJ
Channel temperature	T_{ch}	150	$^\circ C$
Storage temperature range	T_{stg}	-55 to 150	$^\circ C$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

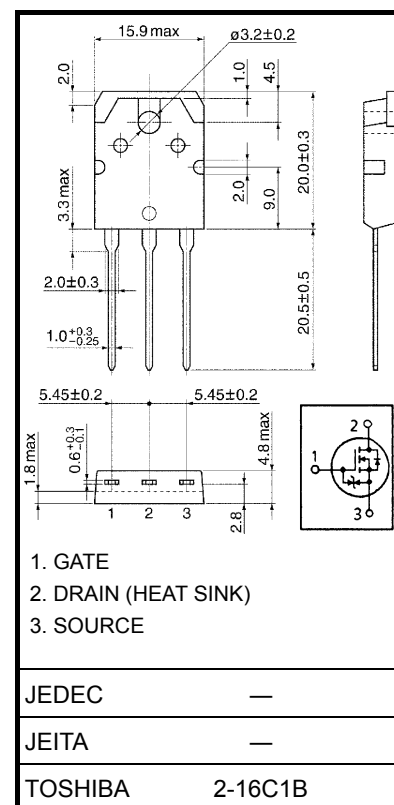
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	1.25	$^\circ C / W$
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	50	$^\circ C / W$

Note 1: Ensure that the channel temperature does not exceed $150^\circ C$.

Note 2: $V_{DD} = 25 V$, $T_{ch} = 25^\circ C$ (initial), $L = 165 \mu H$, $R_G = 25 \Omega$, $I_{AR} = 45 A$

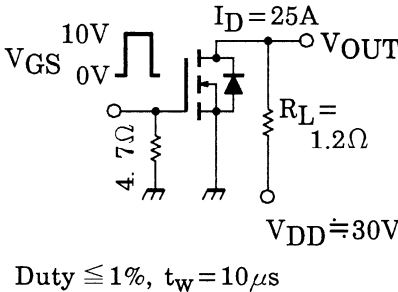
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.
Please handle with caution.



Weight: 4.6 g (typ.)

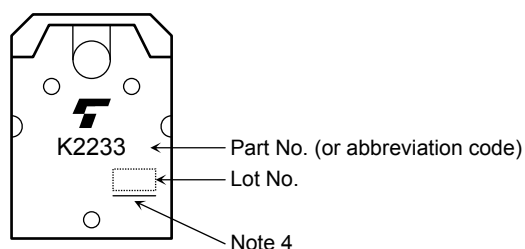
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	—	—	±10	μA
Drain cut-off current		I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V	—	—	100	μA
Drain-source breakdown voltage		V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	60	—	—	V
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	0.8	—	2.0	V
Drain-source ON resistance		R _{DS (ON)}	V _{GS} = 4 V, I _D = 15 A	—	40	55	mΩ
			V _{GS} = 10 V, I _D = 25 A	—	22	30	
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 25 A	15	27	—	S
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	—	1800	—	pF
Reverse transfer capacitance		C _{rss}		—	350	—	
Output capacitance		C _{oss}		—	900	—	
Switching time	Rise time	t _r		—	20	—	ns
	Turn-on time	t _{on}		—	30	—	
	Fall time	t _f		—	40	—	
	Turn-off time	t _{off}		—	130	—	
Total gate charge (Gate-source plus gate-drain)		Q _g	V _{DD} ≈ 48 V, V _{GS} = 10 V, I _D = 45 A	—	60	—	nC
Gate-source charge		Q _{gs}		—	40	—	
Gate-drain ("miller") charge		Q _{gd}		—	20	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	—	—	45	A
Pulse drain reverse current (Note 1)	I _{DRP}	—	—	—	180	A
Forward voltage (diode)	V _{DSF}	I _{DR} = 45 A, V _{GS} = 0 V	—	—	-1.8	V
Reverse recovery time	t _{rr}	I _{DR} = 45 A, V _{GS} = 0 V	—	90	—	ns
Reverse recovered charge	Q _{rr}	dI _{DR} / dt = 100 A / μs	—	0.1	—	μC

Marking

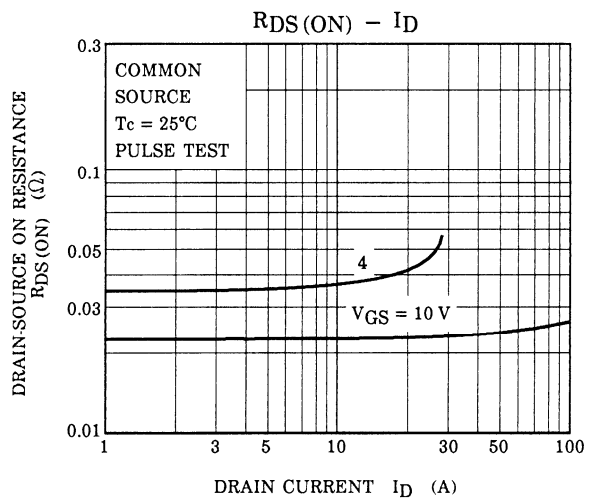
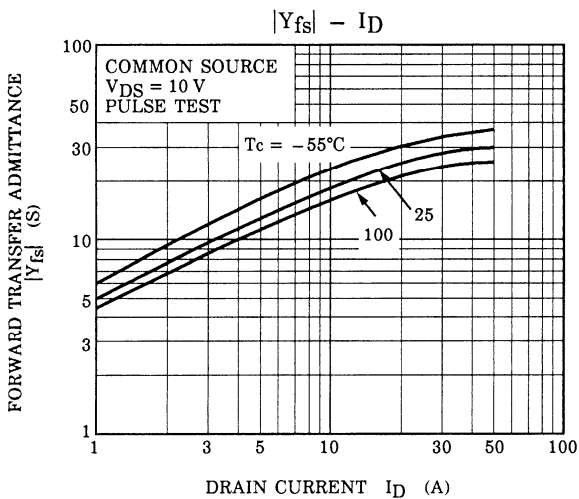
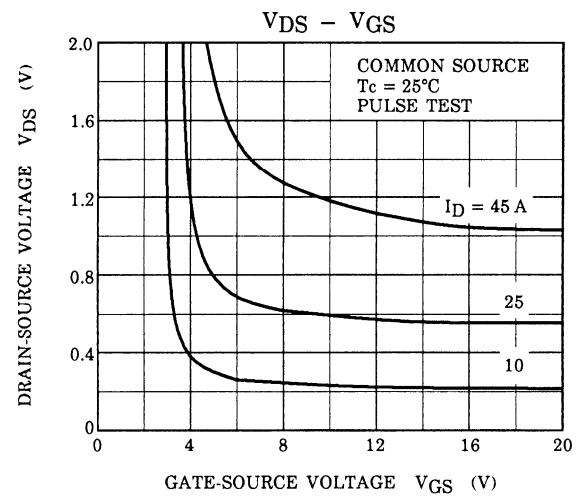
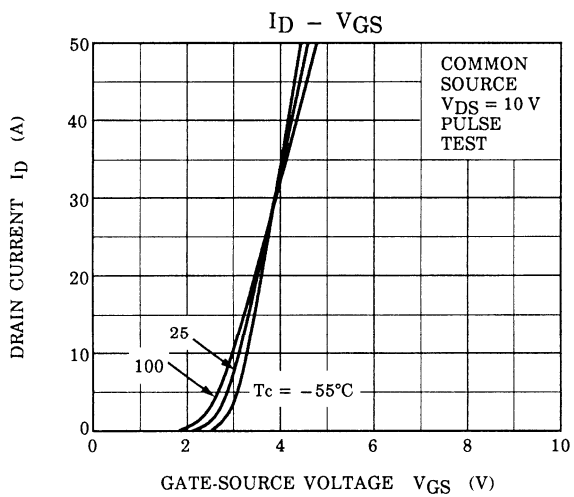
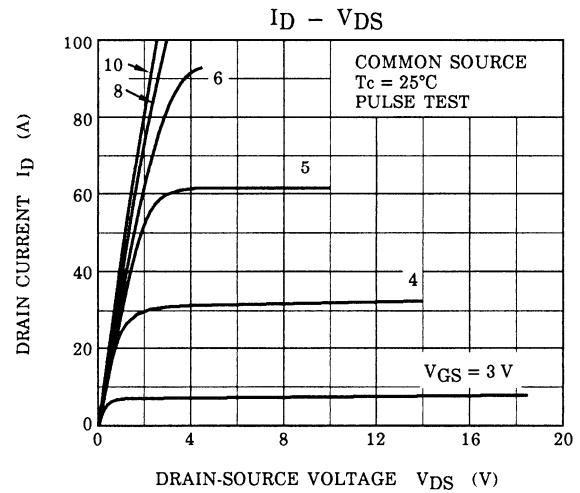
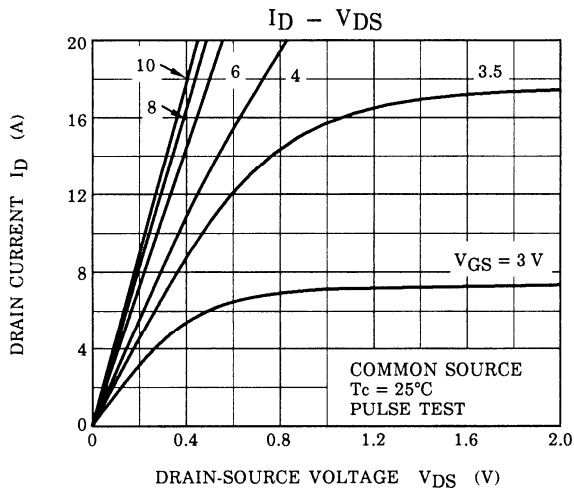


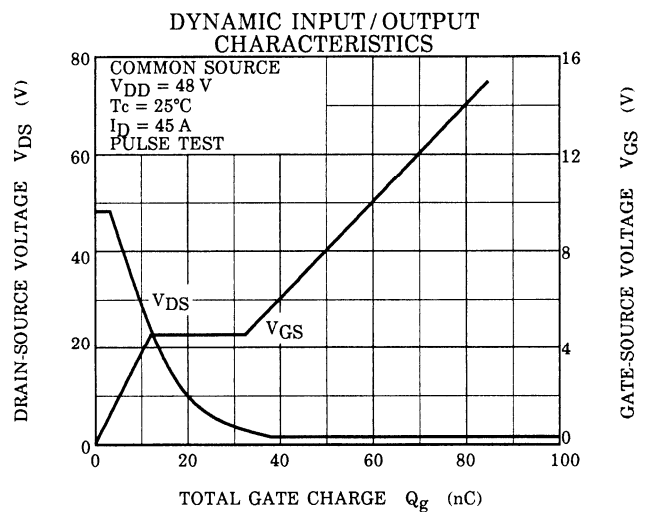
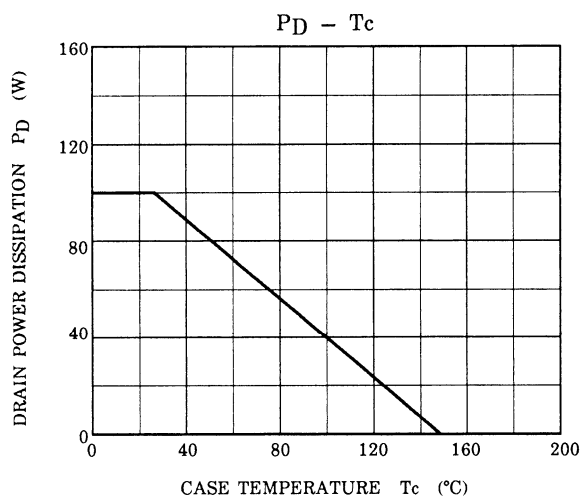
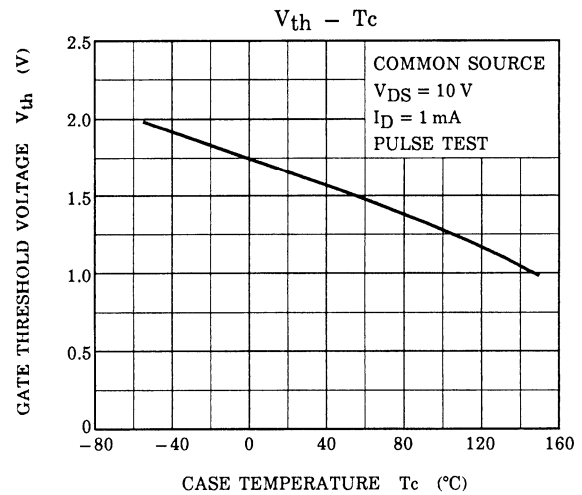
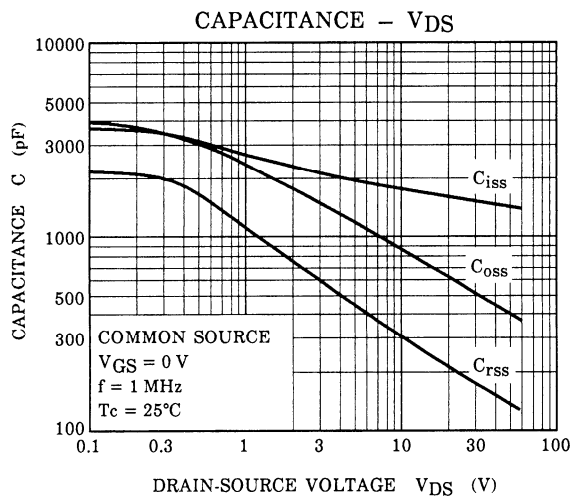
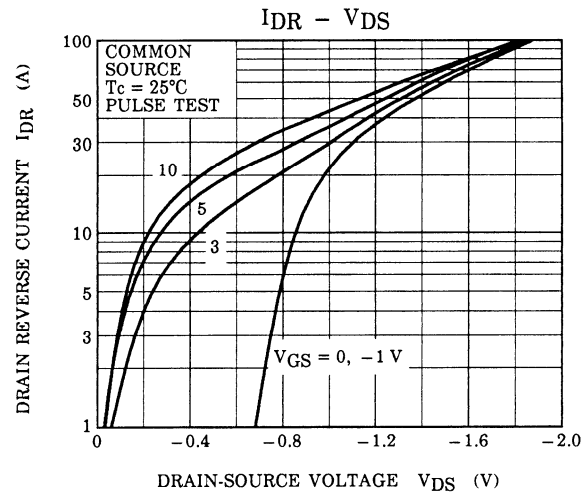
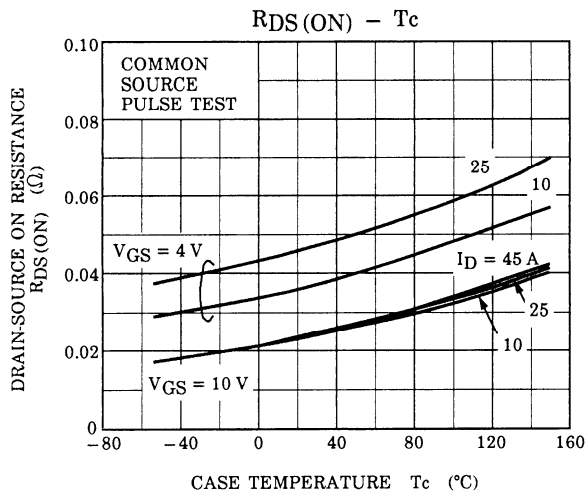
Note 4: A line under a Lot No. identifies the indication of product Labels.

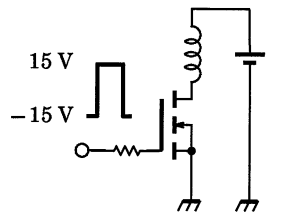
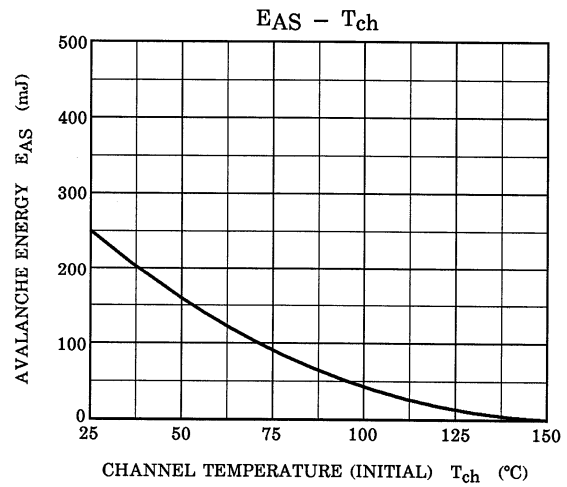
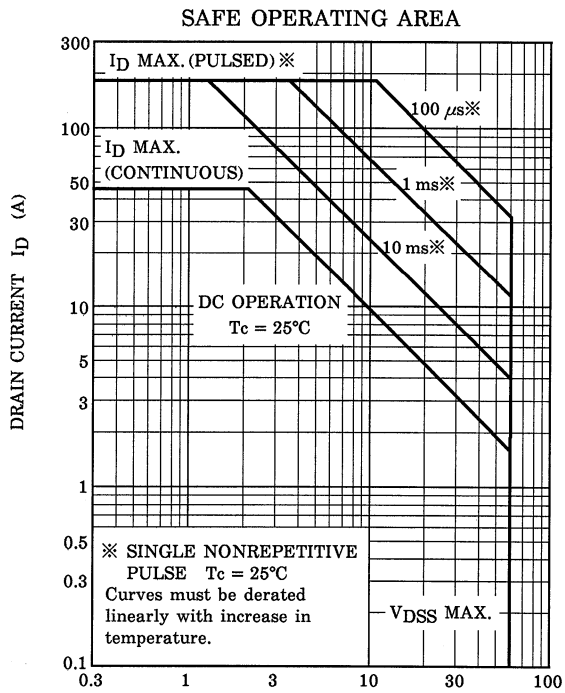
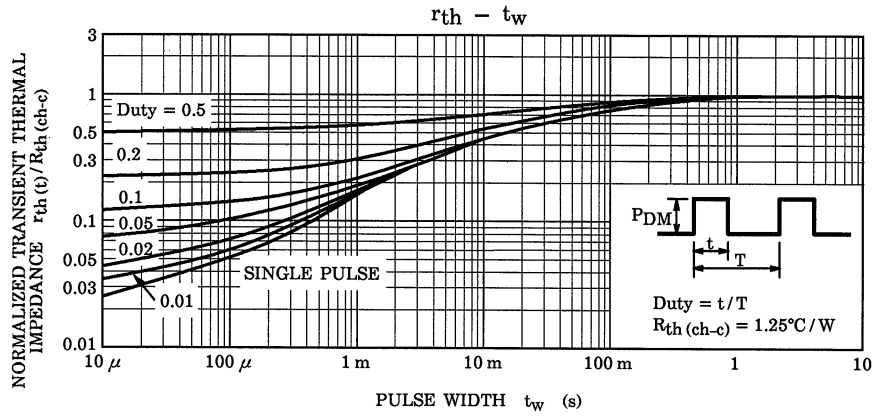
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

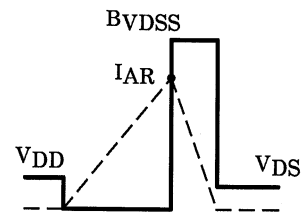
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TEST CIRCUIT



WAVE FORM

$$R_G = 25 \, \Omega$$

$$V_{DD} = 25 \, \text{V}, L = 165 \, \mu\text{H}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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